



200mA Surface Mount Small Signal Diodes

■ Features

- Low profile surface mounted application in order to optimize board space.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Suffix "G" indicates Halogen-free part, ex.BAT42WG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

• Epoxy:UL94-V0 rated flame retardant

• Case: Molded plastic, SOD-123

• Terminals : Solder plated, solderable per

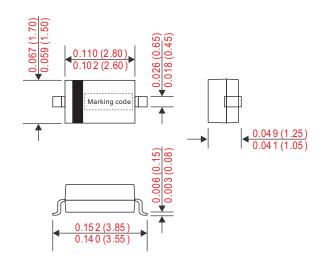
MIL-STD-750, Method 2026

• Polarity : Indicated by cathode band

• Weight: 0.0004 ounce, 0.010 gram

■ Outline

SOD-123



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Tor capacitive road, derate carrent by 2070	•					
Parameter	Cond	Conditions		BAT42W	BAT43W	UNIT
Marking code				S7	S8	UNIT
Peak Repetitive Reverse Voltage			V_{RRM}			
Working Peak Reverse Voltage			V _{RWM}	30		V
DC Blocking Voltage			V _R			
RMS Reverse Voltaget		$V_{R(RMS)}$	21		V	
Average Rectified Output Current			I _{FAV}	2	00	mA
Non-repetitive Peak Forward Surge Current	@ t < 1.0s	I _{FSM}	4.0		А	
Total Device Dissipation			P _D	2	00	mW
Thermal Resistance Junction To Ambient	junction to ambient	R _{eJA}	500		°C/W	
Operating Temperature			T,	-55 ~	+125	°C
Storage Temperature			T _{stg}	-55 ~ +125		°C
Reverse Breakdown Voltage			$V_{(BR)R}$	3	30	V
Forward Voltage	I _F = 200mA	BAT42W, BAT43W			1.0	
	I _F = 10mA	BAT42W			0.4	
	I _F = 50mA	BAT42W	V _F		0.65	V
	I _F = 2.0mA	BAT43W		0.26	0.33	
	I _F = 15mA	BAT43W			0.45	
Reverse Current	$V_R = 25 \text{ V}$ $V_R = 25 \text{ V}, T_J = 100^{\circ}\text{C}$		I _R	0.5		uA
				100		
Junction Capacitance	V _R = 0 V, f = 1.0MHz		Ст	10		pF
Reverse Recover time	$I_F = I_R = 200 \text{mAdc}, I_{rr}$	trr	5.0		ns	

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Revision : C



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■ Rating and characteristic curves

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TA, AMBIENT TEMPERATURE (°C)

Fig. 3 TYPICAL REVERSE CHARACTERISTICS

Fig. 1 FORWARD CURRENT CURVE

100 T_A = 125°C T_A = 75°C T_A = 25°C T_A = -25°C

V_F, FORWARD VOLTAGE (V)

Fig. 2 TYPICAL FORWARD CHARACTERISTIC

1000

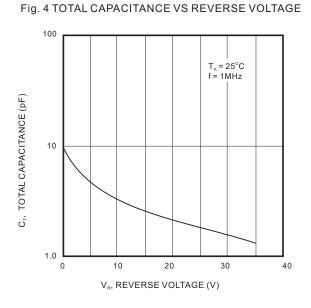
T_A = 125°C

1000

T_A = 75°C

T_A = 25°C

V_R, INSTANTANEOUS REVERSE VOLTAGE (V)



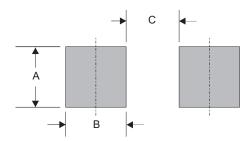
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■ SOD-123 foot print



А	В	С
0.059 (1.50)	0.059 (1.50)	0.094 (2.40)

Dimensions in inches and (millimeters)

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